

SONY®

CXA1096P

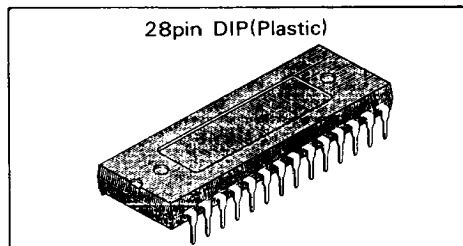
8-bit 20 MSPS Flash A/D Converter (TTL I/O)

Description

CXA1096P is an 8-bit 20 MSPS high speed A/D converter IC. This IC is suitable for a wide range of applications where A/D high speed operation is required.

Features

- Resolution 8-bit $\pm 1/2$ LSB
- High speed operation 20MSPS
- Wide band analog input 8MHz (-3dB)
- Low input capacitance 30pF (Typ.)
- Low power consumption 390mW (Typ.)
- I/O level TTL
- Two ways of power supply (Single +5V or dual +5V/-5.2V)
- Sample and Hold amplifier not required
- Binary or Two's complement mode
- Pin replacable with TDC1048 (TRW)



Structure

Bipolar silicon monolithic IC

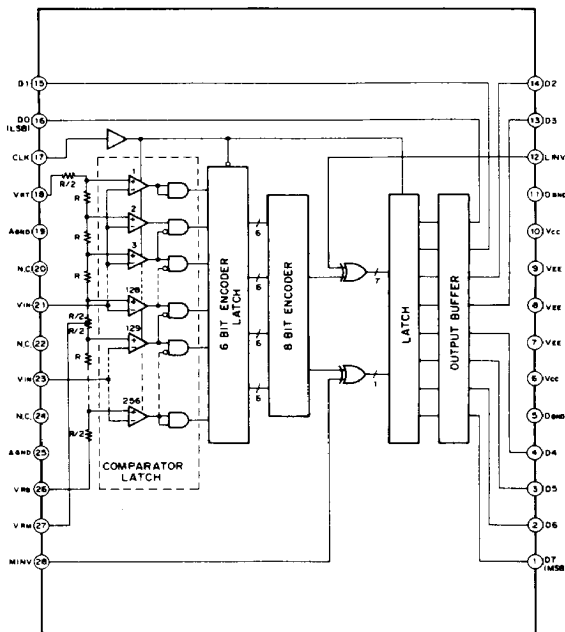
Applications

- Digital TV
- High speed signal processing

Function

8-bit, 20MSPS flash A/D converter

Block Diagram



E89646-HP

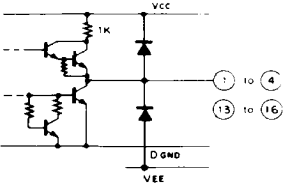
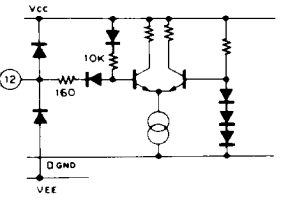
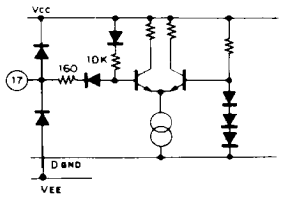
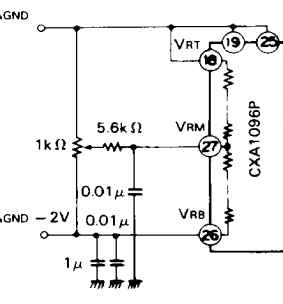
Absolute Maximum Ratings (Ta = 25°C)

• Supply voltage	VCC—DGND	0 to +6	V
	VEE—AGND	0 to -6	V
	AGND—DGND	0 to +6	V
• Input voltage(analog)	VIN	VEE to AGND +0.3	V
• Input voltage (reference)	VRT, VRB, VRM	VEE to AGND +0.3	V
	VRT - VRB	2.5	V
• Input current (VRM)	IVRM	-3 to +3	mA
• Input voltage (digital)	CLK, MINV, LINV	DGND—0.5 to VCC	V
• Storage temperature	Tstg	-55 to +150	°C
• Allowable power dissipation	PD	1.48	W

Recommended Operating Conditions

• Supply voltage	VCC, AGND	4.75to5.25	V
	(Single supply)	DGND, VEE	0
(Dual supply)	VCC	4.75 to 5.25	V
	VEE	-5.5 to -4.75	V
	DGND, AGND	0	V
• Reference input	VRT	AGND -0.1 to AGND +0.1	V
	VRB	AGND -2.2 to AGND -1.8	V
• Analog input	VIN	VRB to VRT	
• Clock pulse width	TPW1	35 (Min.)	ns
	TPW0	10 (Min.)	ns
• Operating temperature	Topr	-20 to +75	°C

Pin Description and Equivalent Circuit

No.	Symbol	Voltage	Equivalent circuit	Description
1 to 4 13 to 16	D0 to D7	TTL		Digital data output pin D0 (LSB) to D7 (MSB)
5, 11	D GND	GND		Digital GND. Separated from A GND.
6, 10	Vcc	5V (Typ.)		Digital power supply
7, 8, 9	VEE	GND (Single supply) - 5V (Dual supply)		Analog power supply
12	LINV	TTL		Input pins for output polarity inversion of D0 (LSB) to D6 (See the Output Coding) when open "1" is maintained.
17	CLK	TTL		Clock input pin
18	VRT	5V (Typ.) (Single supply) GND (Dual supply)		Reference voltage (Upper level)
26	VRB	3V (Typ.) (Single supply) - 2V (Typ.) (Dual supply)		Reference voltage (Lower level)
27	VRM	4V (Typ.) (Single supply) - 1V (Typ.) (Dual supply)		Middle point of reference voltage can be used as the compensation pin for linearity

No.	Symbol	Voltage	Equivalent circuit	Description
19, 25	AGND	5V (Typ.) (Single supply) GND (Dual supply)		Analog power supply
21, 23	V _{IN}	V _{RT} to V _{RB}		Analog input Pin 21 and 23 should be connected together.
28	MINV	TTL		Input pin for output polarity inversion of D7 (MSB) when open "1" is maintained.

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Output Coding

MINV LINV	0 0	0 1	1 0	1 1
AGND	1 1 1 . . . 1 1	1 0 0 . . . 0 0	0 1 1 . . . 1 1	0 0 0 . . . 0 0
.	1 1 1 . . . 1 0	1 0 0 . . . 0 1	0 1 1 . . . 1 0	0 0 0 . . . 0 1
.	.	.	.	.
.	.	.	.	.
V _{IN}	1 0 0 . . . 0 0	1 1 1 . . . 1 1	0 0 0 . . . 0 0	0 1 1 . . . 1 1
.	0 1 1 . . . 1 1	0 0 0 . . . 0 0	1 1 1 . . . 1 1	1 0 0 . . . 0 0
.	.	.	.	.
.	.	.	.	.
AGND-2V	0 0 0 . . . 0 1	0 1 1 . . . 1 0	1 0 0 . . . 0 1	1 1 1 . . . 1 0
.	0 0 0 . . . 0 0	0 1 1 . . . 1 1	1 0 0 . . . 0 0	1 1 1 . . . 1 1

1 : V_{IH}, V_{OH}
0 : V_{IL}, V_{OL}

Electrical Characteristics
(Single supply)
 $V_{CC} = +5V$, $DGND = 0V$, $AGND = +5V$, $V_{EE} = 0V$,
 $V_{RT} = +5V$, $V_{RB} = +3V$, $T_a = 25^{\circ}C$

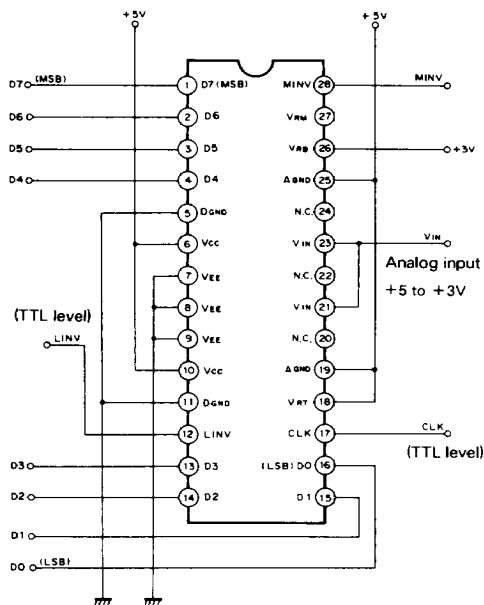
Item	Symbol	Test condition		Min.	Typ.	Max.	Unit
Maximum conversion rate	F_C	$V_{IN} = 5 \text{ to } 3V$ $F_{IN} = F_C/4 - 1 \text{ kHz}$		20			MSPS
Supply current	$I_{CC} + I_{EE}$			56	71	91	mA
Reference pin current	I_{REF}			11	15	18	mA
Analog input bandwidth	BW			8			MHz
Analog input capacitance	C_{IN}	$V_{IN} = 4V + 0.07V_{rms}$			30	35	pF
Analog input bias current	I_{IN}	$V_{IN} = 4V$		15	50	110	μA
Reference resistance (V_{RT} to V_{RB})	R_{REF}				130		Ω
Offset voltage	V_{RT}	E_{OT}		8	13	19	mV
	V_{RB}	E_{OB}		0	5	11	mV
Digital input voltage	V_{IH}			2.0			V
	V_{IL}					0.8	V
Digital input current	I_{IH}	$V_{CC} = \text{Max.}$	$V_{IH} = 2.7V$	0	-100	-150	μA
	I_{IL}		$V_{IL} = 0.5V$	-0.1	-0.32	-0.5	mA
Digital output voltage	V_{OH}	$V_{CC} = \text{Min.}$	$I_{OH} = -500\mu A$	2.7	3.4		V
	V_{OL}		$I_{OL} = 3mA$			0.5	V
Output data delay	T_{DLH}	LOAD 1		15	19	22	ns
	T_{DHL}			22	27	31	ns
Non linearity	E_L	$F_C = 20 \text{ MSPS}$ $V_{IN} = 5 \text{ to } 3V$				$\pm 1/2$	LSB
Differential non linearity	E_D	$F_C = 20 \text{ MSPS}$				$\pm 1/2$	LSB
Differential gain error	DG	NTSC 40 IRE mod. ramp, $F_C = 14.3 \text{ MSPS}$				1.5	%
Differential phase error	DP					0.5	deg.
Aperture jitter	E_{AP}				30		ps
Sampling delay	t_{ds}			5	7	9	ns

Electrical Characteristics
(Dual supply)
 $V_{CC} = +5V$, $DGND = 0V$, $AGND = 0V$, $V_{EE} = -5V$,
 $V_{RT} = 0V$, $V_{RB} = -2V$, $T_a = 25^\circ C$

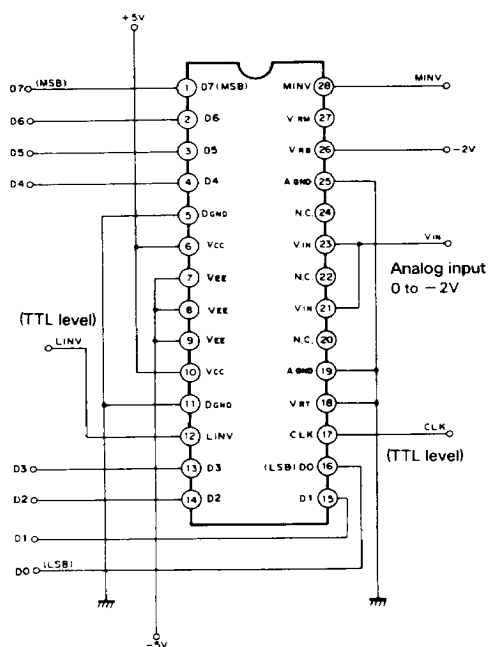
Item		Symbol	Test condition		Min.	Typ.	Max.	Unit
Maximum conversion rate		FC	VIN = 0 to -2V FIN = FC/4 - 1 kHz		20			MSPS
Supply current		ICC			7	10	14	mA
		IEE			50	62	78	mA
Reference pin current		IREF			11	15	18	mA
Analog input bandwidth		BW			8			MHz
Analog input capacitance		CIN	VIN = -1V + 0.07Vrms			30	35	pF
Analog input bias current		IIN	VIN = -1V		15	50	110	μA
Reference resistance (VRT to VRB)		RREF				130		Ω
Offset voltage	VRT	EOT			8	13	19	mV
	VRB	EOB			0	5	11	mV
Digital input voltage		VIH			2.0			V
		VIL					0.8	V
Digital input current		IIH	VCC = Max.	VIH = 2.7V	0	-100	-150	μA
		IIL		VIL = 0.5V	-0.1	-0.32	-0.5	mA
Digital output voltage		VOH	VCC = Min.	IOH = -500μA	2.7	3.4		V
		VOL		IOL = 3mA			0.5	V
Output data delay		TDLH	LOAD 1		15	19	22	ns
		TDHL			22	27	31	ns
Non linearity		EL	FC = 20 MSPS VIN = 0 to -2V				± 1/2	LSB
Differential non linearity		ED	FC = 20 MSPS				± 1/2	LSB
Differential gain error		DG	NTSC 40 IRE mod. ramp, FC = 14.3 MSPS				1.5	%
Differential phase error		DP					0.5	deg.
Aperture jitter		EAP				30		ps
Sampling delay		tds			5	7	9	ns

Application Circuit

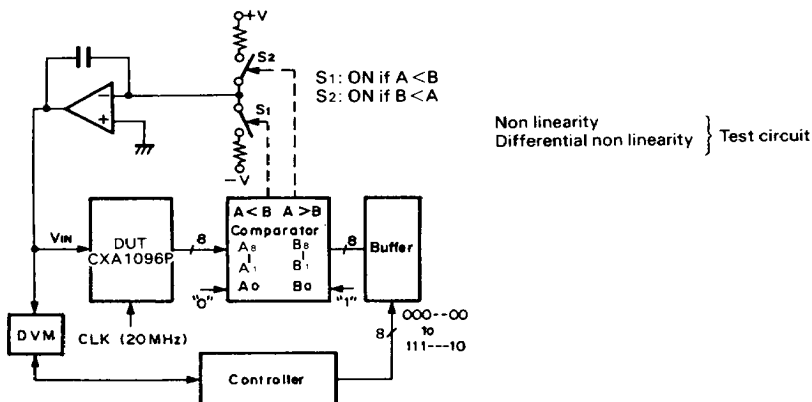
Single supply

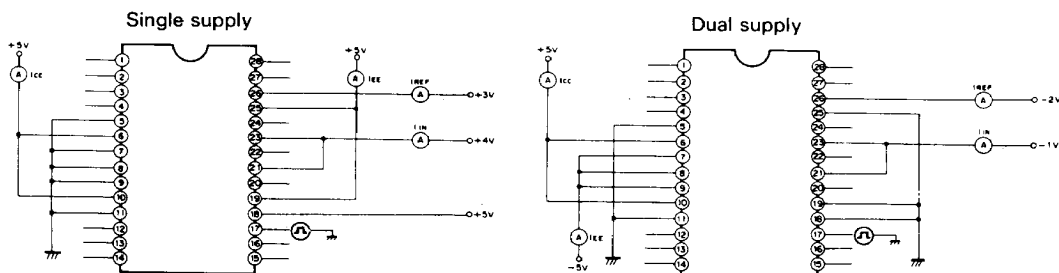
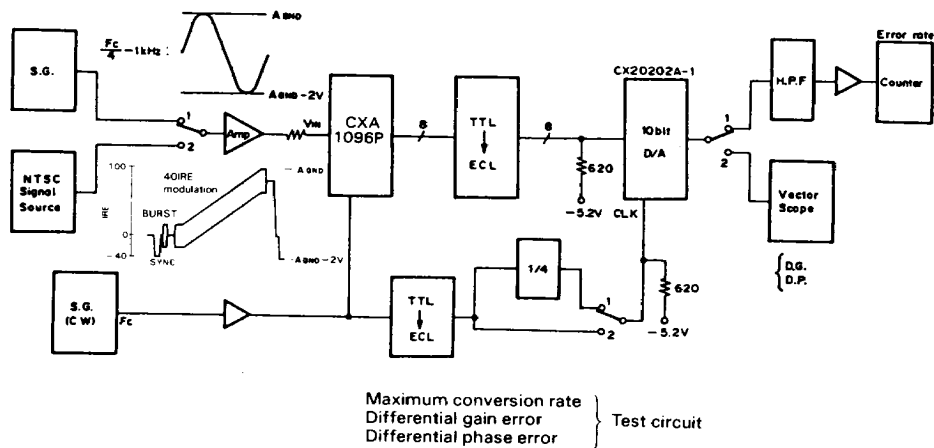


Dual supply



Electrical Characteristics Test Circuit

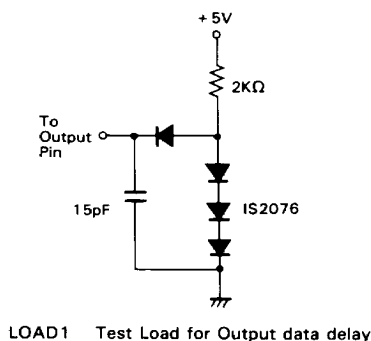
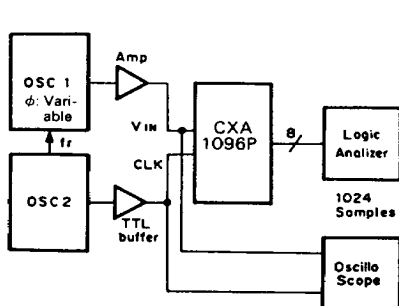


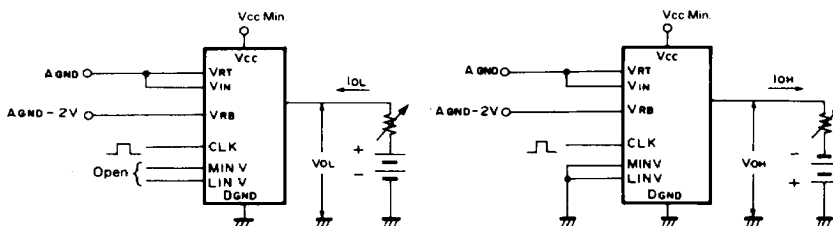


Note) VIN pin is connected to VRT pin for ICC and IEE measurement.

Supply current
Analog input bias current
Reference pin current

Test circuit



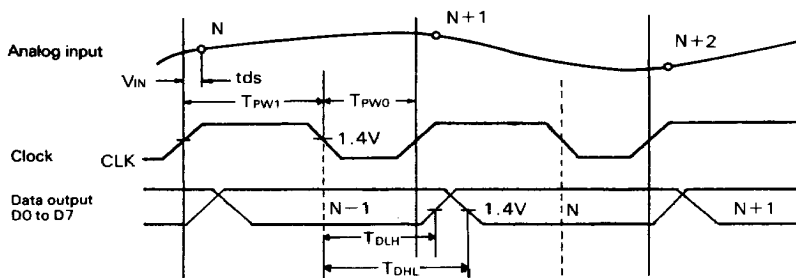


Test circuit of digital output voltage (D0 to D7)

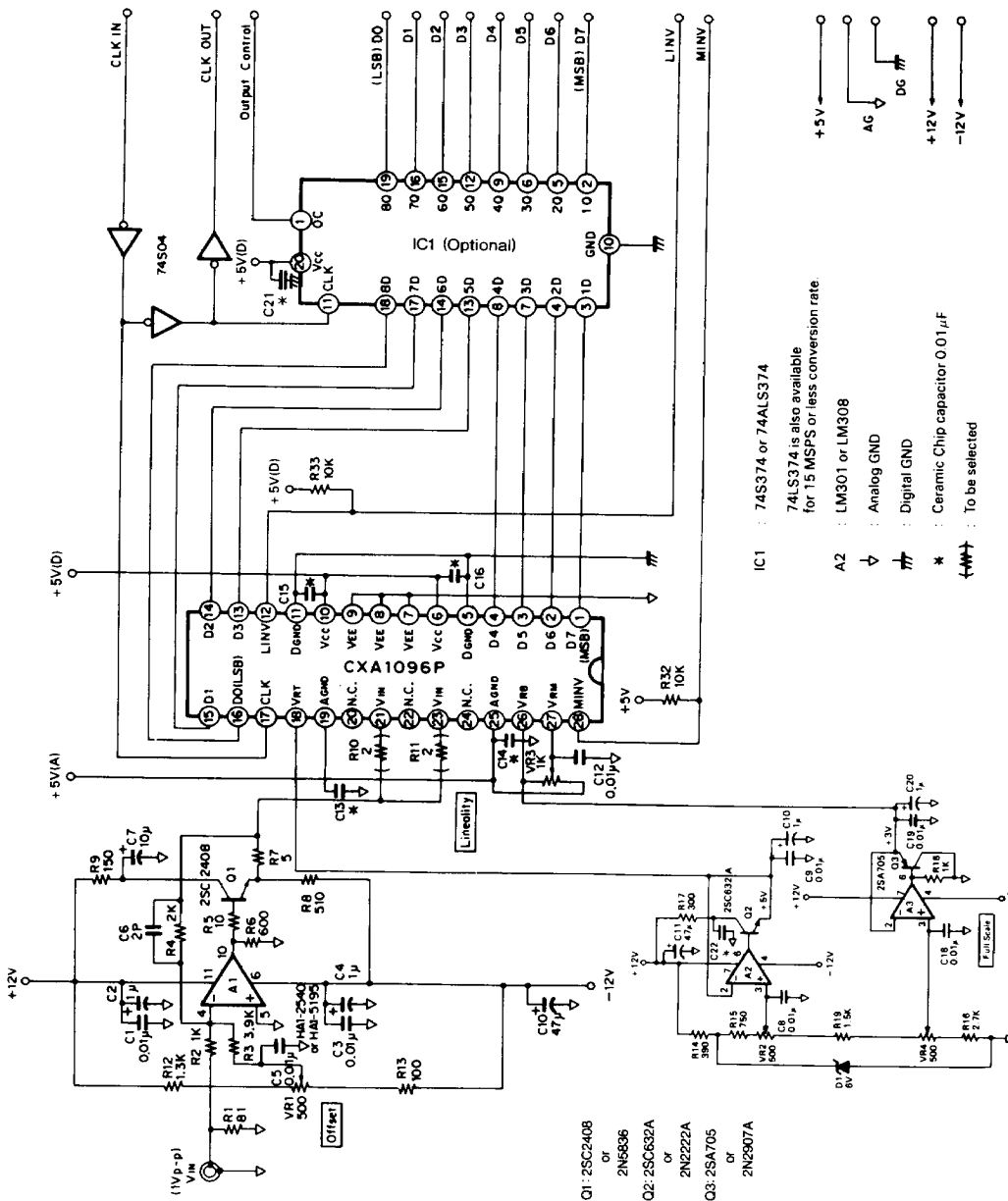


Test circuit of digital input current (CLK, MINV, LINV)

Timing Chart

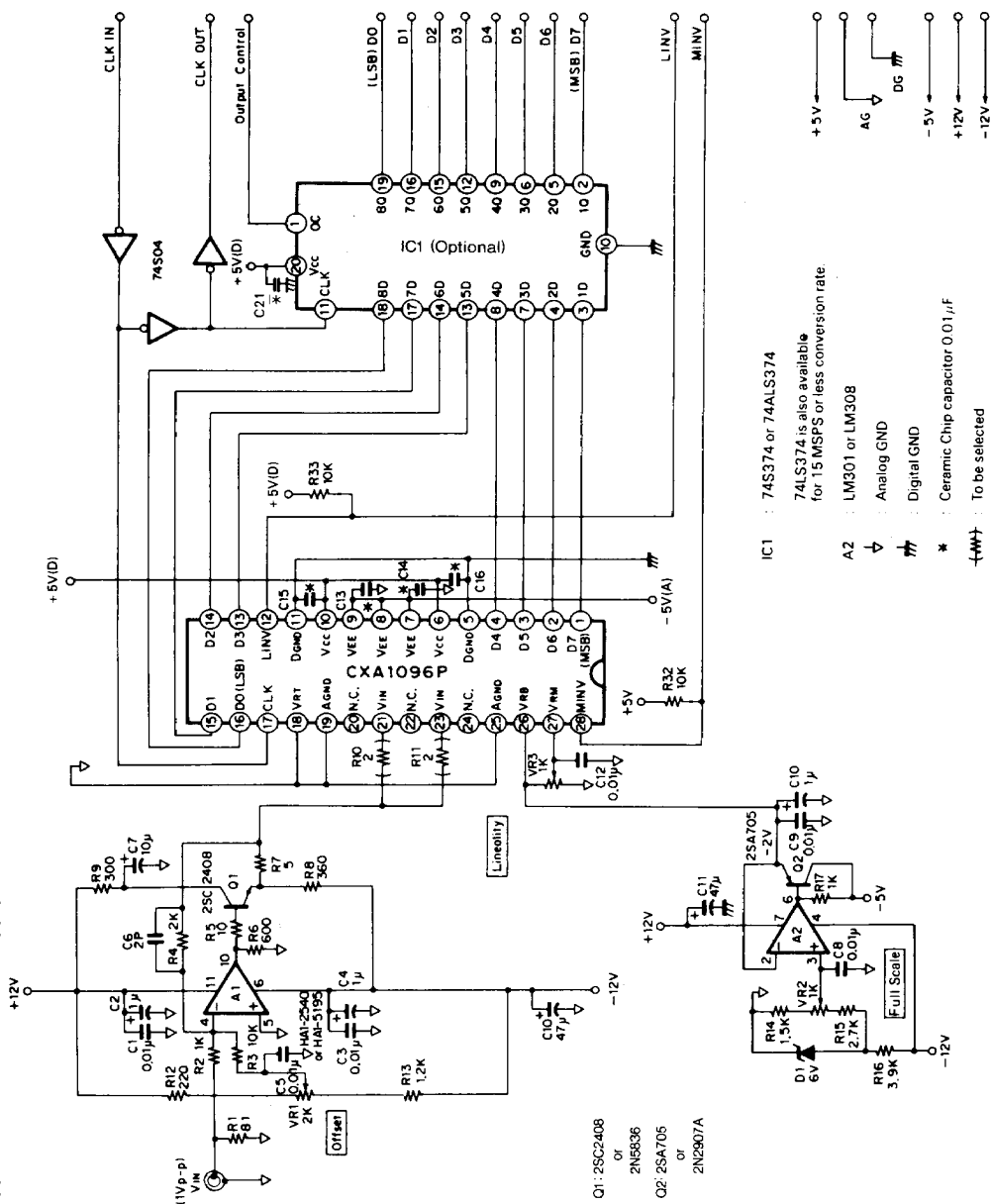


Application Circuit (Single supply)



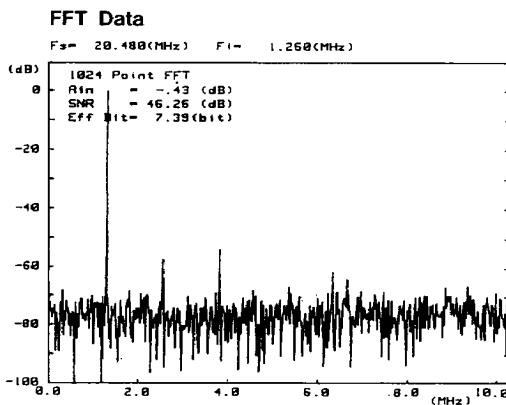
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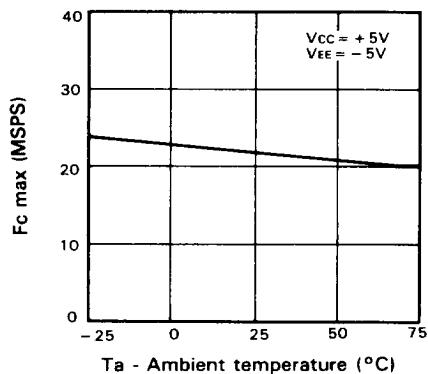
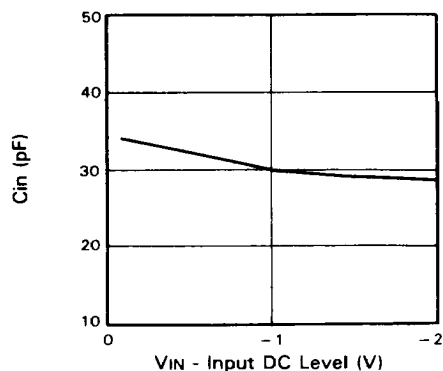
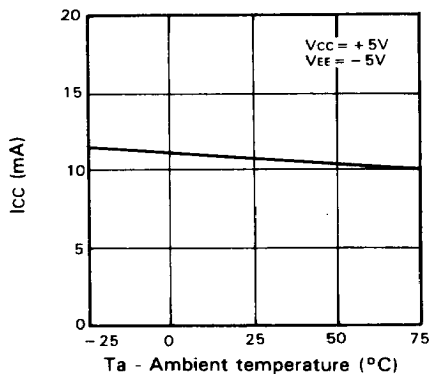
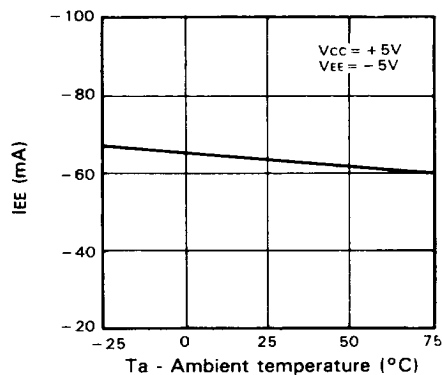
Application Circuit (Dual supply)



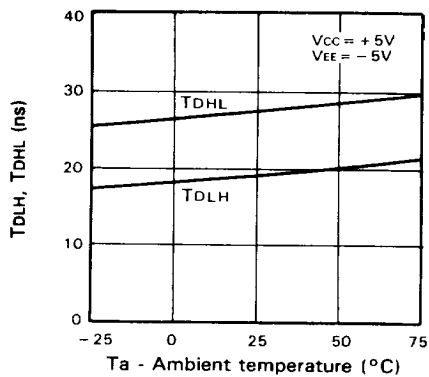
Notes on Application

- Each of DGND pins (5, 11) and each of VCC Pins (6, 10) are divided in internal circuit. All of the pins should be connected to respective PCB patterns.
- Layout of the analog and digital sections should be separated to reduce noise effect.
VEE pins to AGND and VCC pins to DGND should be bypassed as closely as possible by means of $1\mu\text{F}$ and $0.01\mu\text{F}$ capacitors.
For the $0.01\mu\text{F}$, a ceramic chip capacitor should be used.
- The input capacitance of the analog input is much smaller than that of the Flash Type A/D converters in use so far. It is necessary to use an amplifier with sufficient band width and driving power.
Pins VIN (21, 23) are divided in it, so they should be connected together. When driving with a low output impedance amplifier, parasitic oscillation may occur. This can be prevented by introducing between the amplifier output and A/D input a small resistance of 2 to 10Ω with smaller inductance, in series. And, that also each VIN pins are divided with small resistances (shown in the Application Circuit) is effective.
The amplifier output and A/D input should be connected as closely as possible.
- Voltage between VRT to VRB is equivalent to the dynamic range of the analog input. VRB pin should be bypassed to AGND by means of $1\mu\text{F}$ and $0.01\mu\text{F}$ capacitors.
Through bypassing VRM pin with a $0.01\mu\text{F}$ capacitor to AGND, characteristics at high frequency become more balanced. Also, VRM pin can be used as a trimming pin for more precise linearity compensation.
- CLK line should be wired in short distance and that should be separated from the other section to reduce the inductive.
- Analog input signal is sampled at the positive going edge of the CLK, and a corresponding digital data appears to the output parts at the negative going edge with a short delay time (TDLH, TDHL).
If digital data will be latched externally, it should be latched at the negative going edge. (See the Timing Chart)
- It is recommended to connect free pins to AGND for prevention of noise effect.

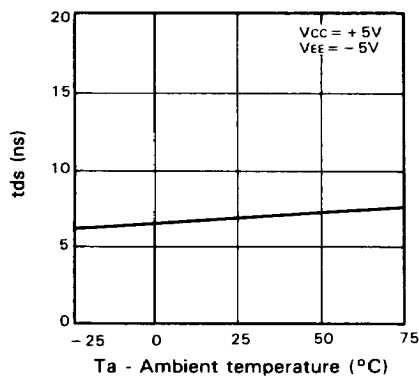


FC max vs. Ambient temperature**CIN vs. VIN - Input DC level****ICC vs. Ambient temperature****IEE vs. Ambient temperature**

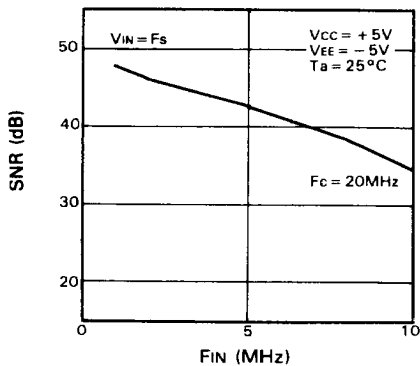
TDLH, TDHL vs. Ambient temperature



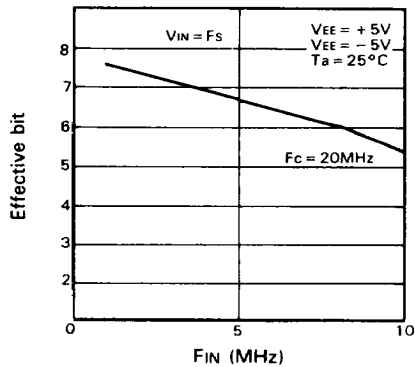
tds vs. Ambient temperature



SNR vs. FIN

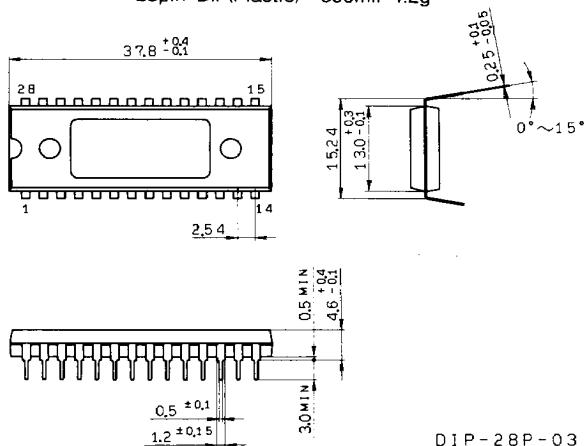


Effective bit vs. FIN



Package Outline Unit : mm

28pin DIP(Plastic) 600mil 4.2g



DIP-28P-03